

Q1C1 高频稳定材料
HIGH FREQUENCY STABLE MATERIALS

Q1C1 为镍锌铁氧体材料，初始磁导率 (μ_i) 约 250，饱和磁通密度 (B_s) 约 335 mT (25 °C) / 240 mT (100 °C)，居里温度高于 140 °C。本材料是高频族的高磁导端点：损耗因子仅 35×10^{-6} (0.5 MHz) / 45×10^{-6} (2.5 MHz)，在此磁导率档位属于相当低的水平，单位匝数感量高，有利于元件小型化。作为 EMI 抑制材料，其标准化阻抗以 RH5 $\times$ 1.5 $\times$ 10 磁珠实测 (曲线见次页)。典型应用为低频 EMI 滤波器、RF 调谐元件与追求小型化的电源模块电感。与 M63 (μ_i 约 180、 $T_c > 300$ °C) 相比，Q1C1 感量密度更高，但居里温度明显较低 (> 140 °C) —— 温度环境严苛时回选 M63 / M61，常温小型化设计则 Q1C1 是本族首选。

Q1C1 is a NiZn ferrite with an initial permeability (μ_i) of approx. 250, a saturation flux density (B_s) of approx. 335 mT at 25 °C (240 mT at 100 °C) and a Curie temperature above 140 °C. It is the high-permeability end of the high-frequency family: a loss factor of only 35×10^{-6} at 0.5 MHz / 45×10^{-6} at 2.5 MHz is remarkably low for this permeability step, and the high inductance per turn favours miniaturisation. As an EMI-suppression material its normalized impedance is measured on an RH5 $\times$ 1.5 $\times$ 10 bead (curve on the next page). Typical uses are low-frequency EMI filters, RF tuning elements and compact power-module inductors. Against M63 (μ_i approx. 180, $T_c > 300$ °C), Q1C1 offers higher inductance density at a clearly lower Curie temperature (> 140 °C) — fall back to M63/M61 in harsh thermal environments; for compact room-temperature designs Q1C1 is the family's first choice.

- Low-Frequency EMI Filter
- RF Tuning Element
- Compact Power-Module Inductor
- EMI Suppression Bead

电磁特性 MAGNETIC CHARACTERISTICS

特性 Characteristic	条件 Condition	值 Value	单位 Unit
初始磁导率 μ_i Initial Permeability	100 kHz & < 0.2 mT	250 $\pm$ 25%	
饱和磁通密度 B_s Saturation Flux Density	3000 A/m · 25 °C 100 Hz	335	mT
饱和磁通密度 B_s Saturation Flux Density	3000 A/m · 100 °C 100 Hz	240	mT
残留磁通密度 B_r Remanence	3000 A/m · 25 °C 100 Hz	200	mT
残留磁通密度 B_r Remanence	3000 A/m · 100 °C 100 Hz	130	mT
矫顽力 H_c Coercivity	3000 A/m · 25 °C 100 Hz	140	A/m
矫顽力 H_c Coercivity	3000 A/m · 100 °C 100 Hz	140	A/m
$\alpha\mu_r$ (温度系数) Temperature coefficient of permeability	20 ~ 60 °C	10	$\times 10^{-6}/K$
相对损耗因子 $\tan\delta/\mu_i$ Relative Loss Factor	0.5 MHz & < 0.2 mT	35	$\times 10^{-6}$
相对损耗因子 $\tan\delta/\mu_i$ Relative Loss Factor	2.5 MHz & < 0.2 mT	45	$\times 10^{-6}$
居里温度 T_c Curie Temp.	100 kHz & < 0.2 mT	> 140	°C
密度 D Density	阿基米德法 Archimedes method	4.9	g/cm ³
电阻率 ρ Volume Resistivity	直流电流 DC Current	10 ⁷	$\Omega \cdot m$

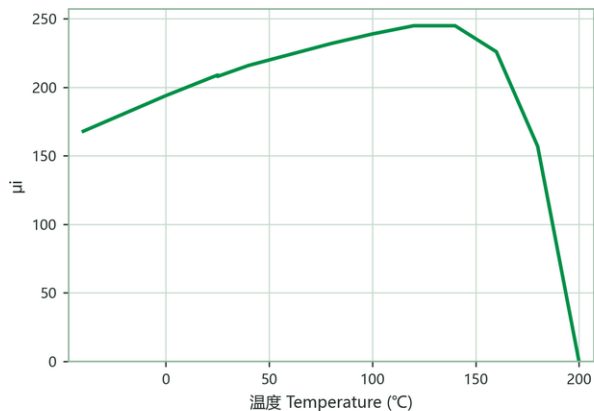
备注：各项数值均为环形磁芯T31 $\times$ 19 $\times$ 8测得的典型数值，由于几何形状和尺寸的影响，产品规格将与这些数据有所差异。
Note: all values are typical data measured on a T31 $\times$ 19 $\times$ 8 toroidal core; actual product specifications will vary with geometry and size.

特性曲线详见次页 CHARACTERISTIC CURVES — SEE NEXT PAGE

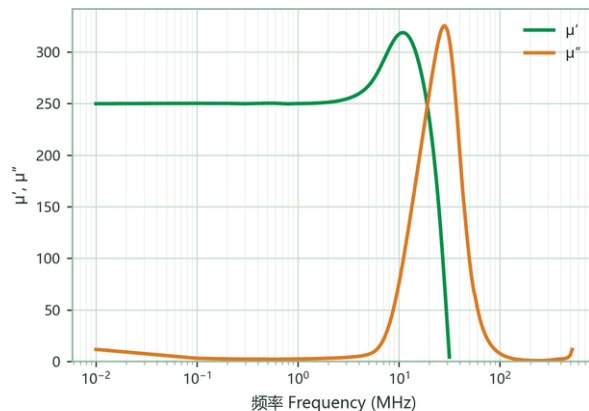
Q1C1

特性曲线

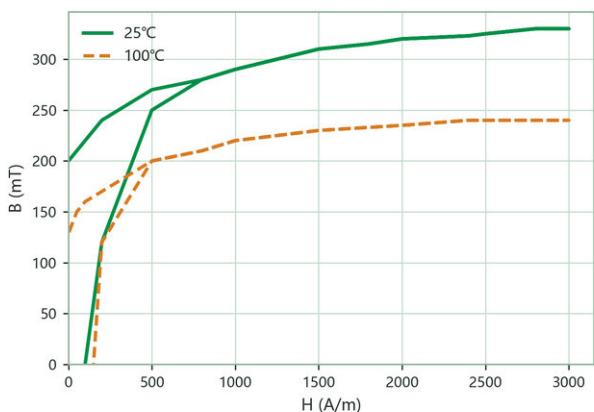
CHARACTERISTIC CURVES



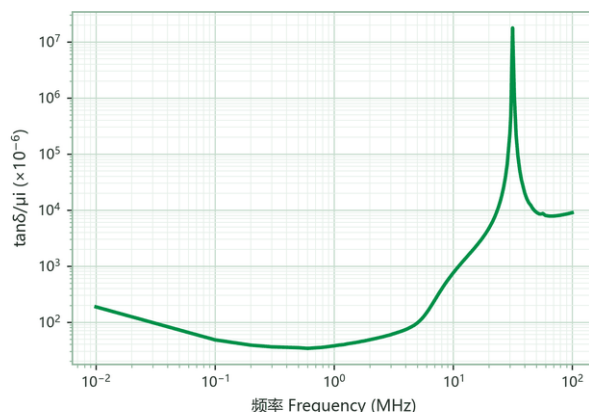
初始磁导率—温度特性
Initial Permeability vs. Temperature



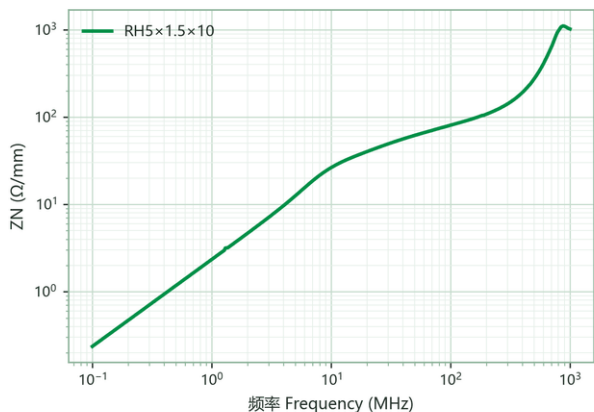
复数磁导率—频率特性
Complex Permeability (μ' , μ'') vs. Frequency



静态磁化曲线
Static Magnetization Curves (B-H)



相对损耗因子—频率特性
Relative Loss Factor ($\tan\delta/\mu_i$) vs. Frequency



标准化阻抗—频率特性 ($\Phi 0.5 \text{ mm}$ 漆包线 100 mm · 单圈测量)
Normalized Impedance ZN vs. Frequency (single turn of $\Phi 0.5 \text{ mm}$ wire, 100 mm long)